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ROUND TYPE LED LAMPS



Lead-Free Parts

**LSBK12343S**

**DATA SHEET**

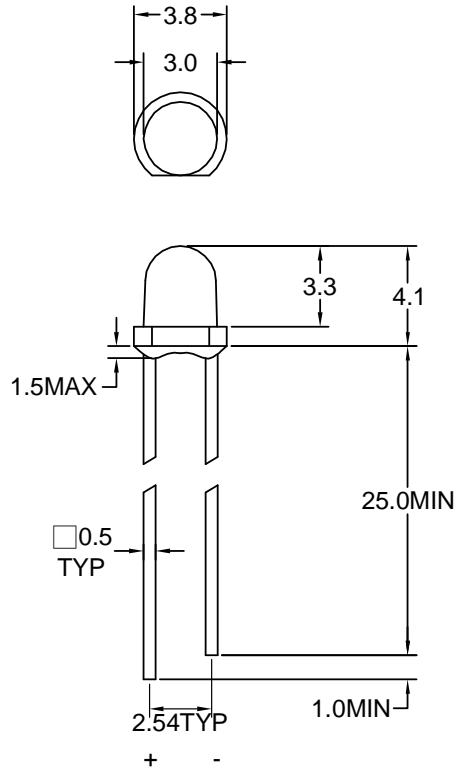
DOC. NO : QW0905-LSBK12343S

REV. : A

DATE : 21 - Apr. - 2008

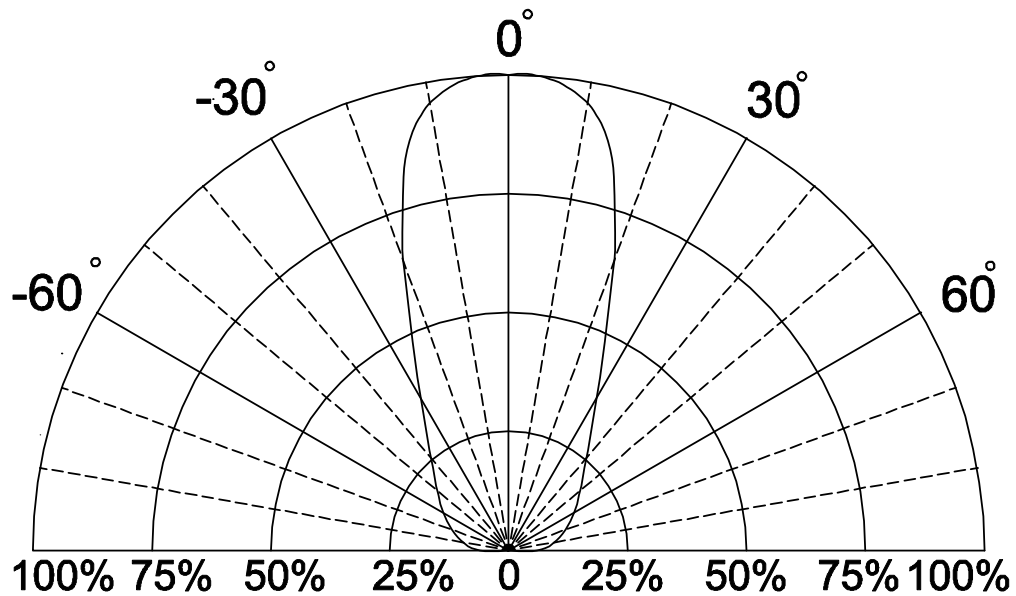


### Package Dimensions



Note : 1.All dimension are in millimeter tolerance is  $\pm 0.25\text{mm}$  unless otherwise noted.  
2.Specifications are subject to change without notice.

### Directivity Radiation



**Absolute Maximum Ratings at Ta=25 °C**

| Parameter                               | Symbol | Ratings    | UNIT |
|---|--------|------------|------|
|   |        | SBKS       |      |
| Forward Current                         | IF     | 30         | mA   |
| Peak Forward Current<br>Duty 1/10@10KHz | IFP    | 100        | mA   |
| Power Dissipation                       | PD     | 120        | mW   |
| Reverse Current @5V                     | Ir     | 50         | μA   |
| Electrostatic Discharge( * )            | ESD    | 500        | V    |
| Operating Temperature                   | Topr   | -20 ~ +80  | °C   |
| Storage Temperature                     | Tstg   | -30 ~ +100 | °C   |

\* Static Electricity or power surge will damage the LED. Use of a conductive wrist band or anti-electrostatic glove is recommended when handling these LED. All devices, equipment and machinery must be properly grounded.

**Typical Electrical & Optical Characteristics (Ta=25 °C)**

| PART NO    | MATERIAL  | COLOR   |             | Dominant wave length<br>λ Dnm | Spectral halfwidth<br>Δλ nm | Forward voltage<br>@20mA(V) |      | Luminous intensity<br>@20mA(mcd) |      | Viewing angle<br>2θ 1/2<br>(deg) |
|------------|-----------|---------|-------------|-------------------------------|-----------------------------|-----------------------------|------|----------------------------------|------|----------------------------------|
|            |           | Emitted | Lens        |                               |                             | Typ.                        | Max. | Min.                             | Typ. |                                  |
| LSBK12343S | InGaN/SiC | Blue    | Water Clear | 475                           | 26                          | 3.5                         | 4.2  | 350                              | 550  | 50                               |

Note : 1.The forward voltage data did not including ±0.1V testing tolerance.  
2. The luminous intensity data did not including ±15% testing tolerance.



### Typical Electro-Optical Characteristics Curve

SBK-S CHIP

Fig.1 Forward current vs. Forward Voltage

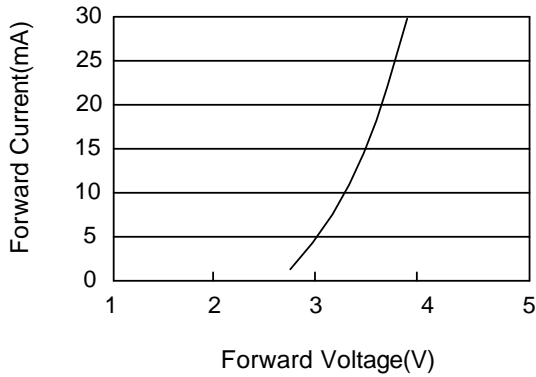


Fig.2 Relative Intensity vs. Forward Current

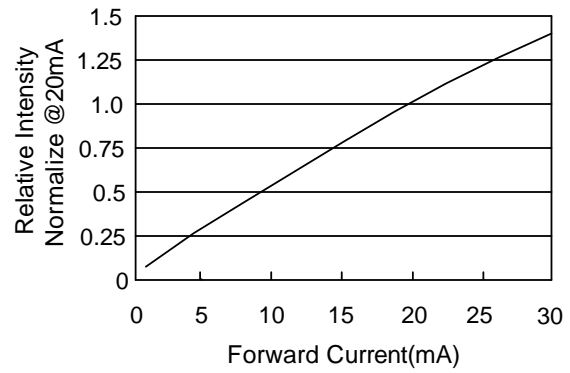


Fig.3 Forward Current vs. Temperature

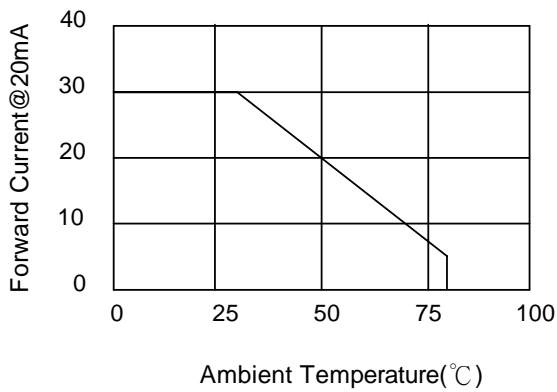
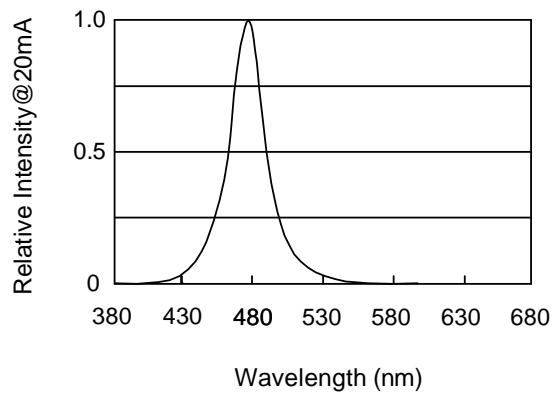


Fig.4 Relative Intensity vs. Wavelength





### Soldering Condition(Pb-Free)

#### 1.Iron:

Soldering Iron:30W Max

Temperature 350 ° C Max

Soldering Time:3 Seconds Max(One time only)

Distance:2mm Min(From solder joint to body)

#### 2.Wave Soldering Profile

Dip Soldering

Preheat: 120° C Max

Preheat time: 60seconds Max

Ramp-up

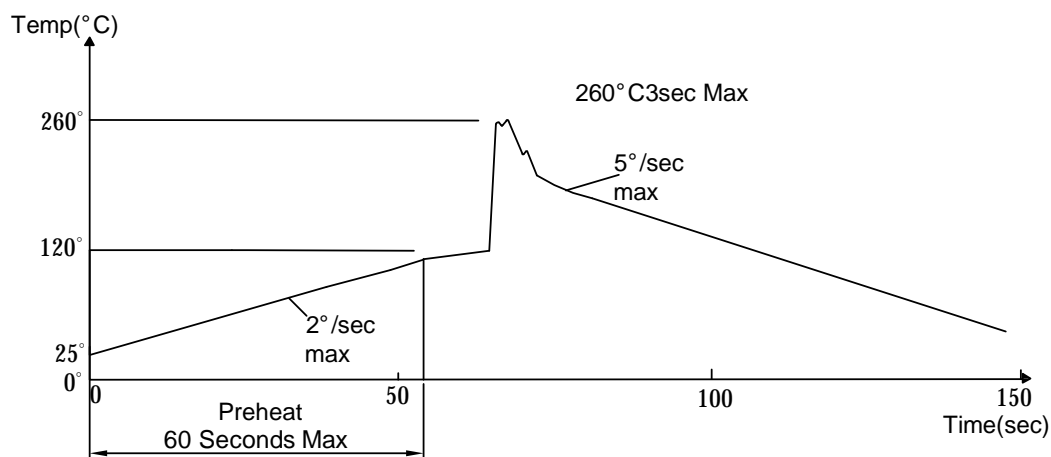
2° C/sec(max)

Ramp-Down:-5° C/sec(max)

Solder Bath:260° C Max

Dipping Time:3 seconds Max

Distance:2mm Min(From solder joint to body)



- Note: 1.Wave solder should not be made more than one time.  
2.You can just only select one of the soldering conditions as above.



## Reliability Test:

| Test Item                           | Test Condition   | Description   | Reference Standard   |
|-------------------------------------|--|---|--|
| Operating Life Test                 | 1.Under Room Temperature<br>2.If=20mA<br>3.t=1000 hrs (-24hrs, +72hrs) | This test is conducted for the purpose of determining the resistance of a part in electrical and thermal stressed.  | MIL-STD-750: 1026<br>MIL-STD-883: 1005<br>JIS C 7021: B-1                      |
| High Temperature Storage Test       | 1.Ta=105 °C±5°C<br>2.t=1000 hrs (-24hrs, +72hrs)                       | The purpose of this is the resistance of the device which is laid under condition of high temperature for hours.  | MIL-STD-883:1008<br>JIS C 7021: B-10   |
| Low Temperature Storage Test        | 1.Ta=-40 °C±5°C<br>2.t=1000 hrs (-24hrs, +72hrs)                       | The purpose of this is the resistance of the device which is laid under condition of low temperature for hours.   | JIS C 7021: B-12   |
| High Temperature High Humidity Test | 1.Ta=65 °C±5°C<br>2.RH=90%~95%<br>3.t=240hrs ±2hrs                     | The purpose of this test is the resistance of the device under tropical for hours.  | MIL-STD-202:103B<br>JIS C 7021: B-11   |
| Thermal Shock Test                  | 1.Ta=105 °C±5°C & -40°C±5°C (10min) (10min)<br>2.total 10 cycles       | The purpose of this is the resistance of the device to sudden extreme changes in high and low temperature.  | MIL-STD-202: 107D<br>MIL-STD-750: 1051<br>MIL-STD-883: 1011                    |
| Solder Resistance Test              | 1.T.Sol=260 °C±5°C<br>2.Dwell time= 10 ±1sec.                          | This test intended to determine the thermal characteristic resistance of the device to sudden exposures at extreme changes in temperature when soldering the lead wire. | MIL-STD-202: 210A<br>MIL-STD-750: 2031<br>JIS C 7021: A-1                      |
| Solderability Test                  | 1.T.Sol=230 °C±5°C<br>2.Dwell time=5 ±1sec                             | This test intended to see soldering well performed or not.  | MIL-STD-202: 208D<br>MIL-STD-750: 2026<br>MIL-STD-883: 2003<br>JIS C 7021: A-2 |